

Green Products

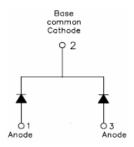
MBR2080CTL SCHOTTKY RECTIFIER

Applications:

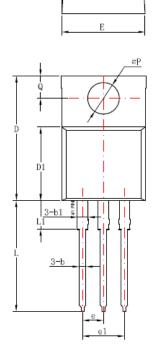
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

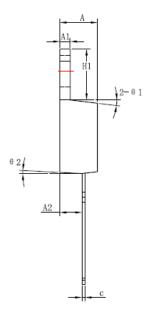
Features:

- 150 °C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · High frequency operation
- . Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In mm





Symbol	Dimensions in millimeters			
_	Min	Typical	Max	
Α	4.42	4.42 4.57		
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1		5.06		
H1	6.04	6.24	6.44	
L	12.7	13.56	13.78	
L1		3.5		
ФР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		

TO-220AB

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Marking Diagram:



Where XXXXX is YYWWL

MBR = Device Type

= Forward Current (20A) 80 = Reverse Voltage (80V)

CTL = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBR2080CTL	TO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	80	V
Average Rectified Forward Current	Io	50Hz Full Sine Wave Resistive Load @T _C =100 °C, V _{RM} =40V	20	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	50Hz Full Sine Wave	180	Α

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Electrical Characteristics:

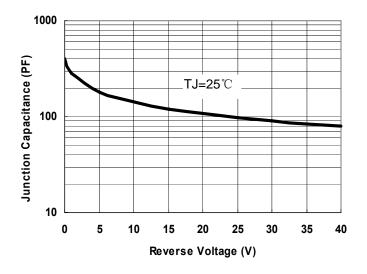
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V_{F1}	@ 10 A, Pulse, T _J = 25 °C	0.75	V
Max. Reverse Current (per leg) *	I _{R1}	$@V_R = \text{rated } V_R$ $T_C = 25 ^{\circ}\text{C}$	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_C = 125 ^{\circ}C$	50	mA
Max. Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 \text{ °C}$ $f_{SIG} = 1MHz$	500	pF
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ ext{ heta}JC}$	DC operation	2.0	°C/W
Approximate Weight	wt	-	2.0	g
Case Style	TO-220AB			

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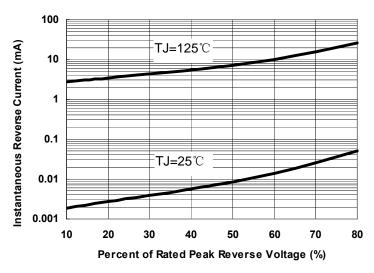


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

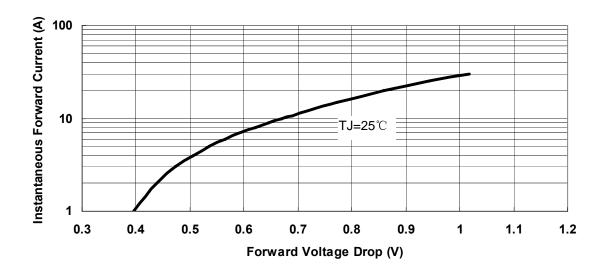


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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